



M T B F

(E I A J R C R - 9 1 0 2)

Model	MGW64812
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No.	P a r t s		Q'ty of Device	Failure rate [10 ⁻⁶ /H]	R e f e r e n c e
1	I C	Monolithic	3	0.0720	
2		Hybrid	0	0.0000	
3	Transistors		4	0.2002	
4	Diodes		8	0.1630	
5	LED•Optocouplers		1	0.0700	
6	Resistors		28	0.3254	
7	Capacitors		24	0.1776	
8	Transformer•Choke Coil		3	0.0690	
9	Connectors		193	0.0264	
10	Others		2	0.2200	
Total Failure Rate [10 ⁻⁶ /H]				1.3236	

M T B F	[H]	756,000
Ambient Temperature	[℃]	—
Load Factor	[%]	—